## MDV03-400

## ULTRA-FAST RECOVERY DIODE

MAJOR PRODUCTS CHARACTERISTICS

| $\mathbf{I}_{\mathrm{F}(\mathrm{AV})}$ | 3 A |
| :---: | :---: |
| $\mathrm{~V}_{\mathrm{RRM}}$ | 400 V |
| $\mathrm{t}_{\mathrm{rr}}$ | 25 ns |
| $\mathrm{~V}_{\mathrm{F}}$ (max) | 1.4 V |

## FEATURES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING


## DESCRIPTION

Ultra-fast diode especially designed for modulation and flyback rectification in standard and high resolution displays for TV's and monitors.
The device is packaged in a DO-201AD axial enveloppe.

PRELIMINARY DATASHEET


ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| VRRM | Repetitive peak reverse voltage |  | 400 | V |
| $\mathrm{V}_{\text {RSM }}$ | Non repetitive peak reverse voltage |  | 440 | V |
| IFRM | Repetive peak forward current | $t_{p} \leq 10 \mu s$ | 60 | A |
| $\mathrm{IF}(\mathrm{AV})$ | Average forward current* | $\begin{aligned} & \mathrm{T}_{\mathrm{a}}=65^{\circ} \mathrm{C} \\ & \delta=0.5 \end{aligned}$ | 3 | A |
| IFSM | Surge non repetitive forward current | $\begin{aligned} & t_{p}=10 \mathrm{~ms} \\ & \text { Sinusoidal } \end{aligned}$ | 60 | A |
| P | Power dissipation * | $\mathrm{T}_{\mathrm{a}}=65^{\circ} \mathrm{C}$ | 4.2 | W |
| $\begin{gathered} \mathrm{T}_{\mathrm{stg}} \\ \mathrm{~T}_{\mathrm{j}} \end{gathered}$ | Storage and junction temperature range |  | $\begin{aligned} & -40 \text { to }+150 \\ & -40 \text { to }+150 \end{aligned}$ | ${ }^{\circ} \mathrm{C}$ |

## THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $R_{\text {th }(\mathrm{j}-\mathrm{I})}$ | Junction to lead | 20 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $R_{\text {th }(\mathrm{j}-\mathrm{a})}$ | Junction to ambient on printed circuit L lead = 10mm | 75 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

* On infinite heatsink with 10 mm lead lengh.

MDV03-400
STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions |  | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{R}}$ * | Reverse Leakage Current | $\mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\text {RRM }}$ | $\begin{aligned} & \mathrm{Tj}=25^{\circ} \mathrm{C} \\ & \mathrm{Tj}=100^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 0.5 \end{aligned}$ | $\underset{\mathrm{mA}}{\mu \mathrm{~A}}$ |
| $\mathrm{V}_{\mathrm{F}}$ ** | Forward Voltage Drop | $\mathrm{IF}_{\mathrm{F}}=3 \mathrm{~A}$ | $\begin{aligned} & \mathrm{Tj}=25^{\circ} \mathrm{C} \\ & \mathrm{Tj}=100^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{array}{r} 1.5 \\ 1.4 \end{array}$ | $\mathrm{V}$ |

Pulse test : *tp=5ms, $\delta<2 \%$

$$
{ }^{* *} \mathrm{tp}=380 \mu \mathrm{~s}, \delta<2 \%
$$

DYNAMIC ELECTRICAL CHARACTERISTICS
TURN-OFF SWITCHING

| Symbol | Parameter | Test Conditions | Typ. | Max. | Unit |
| :---: | :---: | :--- | :---: | :---: | :---: |
| trr | Reverse Recovery Time | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A} \mathrm{di} / \mathrm{dt}=-15 \mathrm{~A} / \mu \mathrm{s}$ <br> $\mathrm{V}_{\mathrm{R}}=30 \mathrm{~V}$ |  | 55 | ns |
|  |  | $\mathrm{I}_{\mathrm{F}}=0.5 \mathrm{~A} \quad \mathrm{I}_{\mathrm{R}}=1 \mathrm{~A} \quad \operatorname{Irr}=0.25 \mathrm{~A}$ |  | 25 | ns |

DYNAMIC ELECTRICAL CHARACTERISTICS
TURN-ON SWITCHING

| Symbol | Parameter | Test Conditions | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tfr | Forward Recovery Time | $\mathrm{I}_{\mathrm{F}}=3 \mathrm{~A} \quad \mathrm{~d} \mathrm{l}_{\mathrm{F}} / \mathrm{dt}=60 \mathrm{~A} / \mu \mathrm{s}$ Measured at $1.1 \mathrm{~V}_{\mathrm{F}}$ max. $\mathrm{Tj}=25^{\circ} \mathrm{C}$ |  | 250 | ns |
| VFP | Peak Forward Voltage |  |  | 13 | V |

To evaluate the maximum conduction losses use the following equation :
$P=\frac{1.10 \times I_{0}}{2} \times \delta+\frac{0.050 \times I_{p}^{\wedge} 2}{3} \times \delta$
$\delta$ : duty cycle
$I_{p}:$ Peak current
Ex: for $\mathrm{I}_{\mathrm{p}}=3 \mathrm{~A}$ and $\delta=0.5, \mathrm{P}=0.9$ Watts.

## PACKAGE MECHANICAL DATA

DO-201AD (Plastic)


| REF. | DIMENSIONS |  |  |  | NOTES |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Millimeters |  | Inches |  |  |
|  | Min. | Max. | Min. | Max. |  |
| A |  | 9.50 |  | 0.374 | 1 - The lead diameter $\varnothing \mathrm{D}$ is not controlled over zone E <br> 2 - The minimum axial lengh within which the device may be placed with its leads bent at right angles is 0.59 " $(15 \mathrm{~mm})$ |
| B | 25.40 |  | 1.000 |  |  |
| $\varnothing \mathrm{C}$ |  | 5.30 |  | 0.209 |  |
| $\varnothing \mathrm{D}$ |  | 1.30 |  | 0.051 |  |
| E |  | 1.25 |  | 0.049 |  |

Weight: 1 g
Marking : Type number - Date code
White band indicated cathode cooling methode : by convertion (method A)

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